

# Photointerrupters(Transmissive)

KODENSHI

SG - 268

The SG - 268 photointerrupter high - performance standard type, combines high - output GaAs IRED with high sensitive phototransistor.

## FEATURES

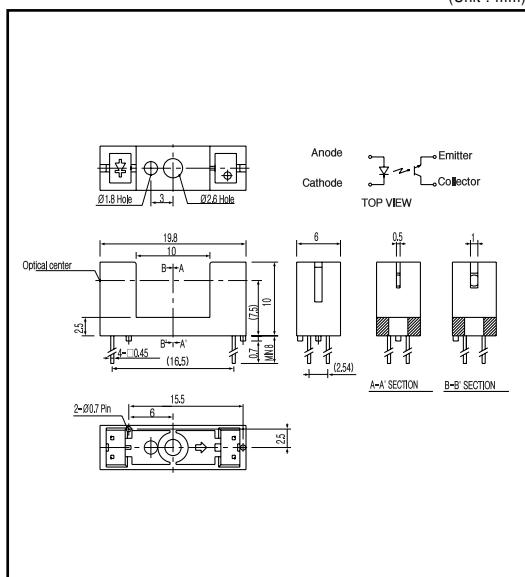
- PWB direct mount type
- GAP : 10.0mm
- With the installation positioning boss
- Single-side screw-mount

## APPLICATIONS

- Analysis machines
- Optical switches
- Amusement machines
- PPC

## DIMENSIONS

(Unit : mm)



## MAXIMUM RATINGS

(Ta=25 °C)

Item	Symbol	Rating	Unit
Input	P <sub>D</sub>	100	mW
	I <sub>F</sub>	60	mA
	V <sub>R</sub>	5	V
	I <sub>FP</sub>	1	A
Output	P <sub>C</sub>	100	mW
	I <sub>C</sub>	40	mA
	V <sub>CEO</sub>	30	V
	V <sub>ECD</sub>	5	V
Operating temp. <sup>-2</sup>		Topr.	-20~+85
Storage temp. <sup>-2</sup>		Tstg.	-30~+85
Soldering temp. <sup>-3</sup>		Tsol.	260

\*1. pulse width : t w 100 sec, period : T=10msec.

\*2. No icebound or dew

\*3. For MAX.5 seconds at the position of 1mm from the package

## ELECTRO-OPTICAL CHARACTERISTICS

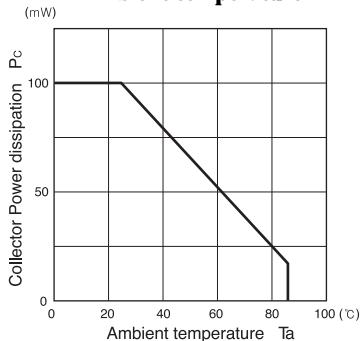
(Ta=25 °C)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit.
Input	V <sub>F</sub>	I <sub>F</sub> =20mA		1.2	1.4	V
	I <sub>R</sub>	V <sub>R</sub> =5V			10	μA
	p	I <sub>F</sub> =20mA		940		nm
Output	I <sub>CEO</sub>	I <sub>C</sub> =10V		1	100	nA
	I <sub>CEOD</sub>	I <sub>C</sub> =20mA, V <sub>E</sub> =5V, Non-shading	0.1		2.5	mA
Transmiss.	I <sub>light</sub>	I <sub>C</sub> =20mA, V <sub>E</sub> =5V, Non-shading		0.1	1	μA
	I <sub>leakage</sub>	I <sub>C</sub> =20mA, V <sub>E</sub> =5V(shading)			0.15	0.4
	V <sub>CE(sat)</sub>	I <sub>C</sub> =20mA, I <sub>C</sub> =0.1mA			0.4	V
Rise time	tr	V <sub>CC</sub> =5V, I <sub>C</sub> =2mA, R=100		4		usec.
	tf			5		usec.

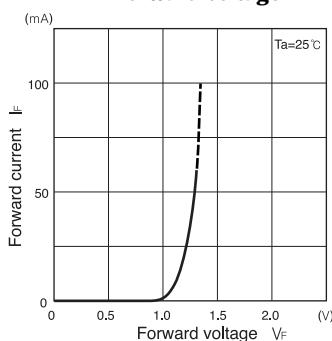
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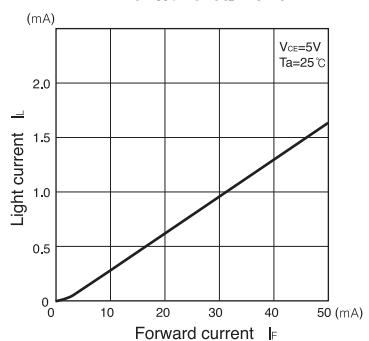
**Collector power dissipation Vs.  
Ambient temperature**



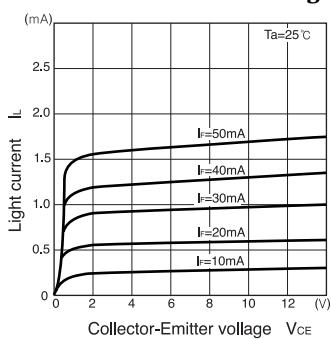
**Forward current Vs.  
Forward voltage**



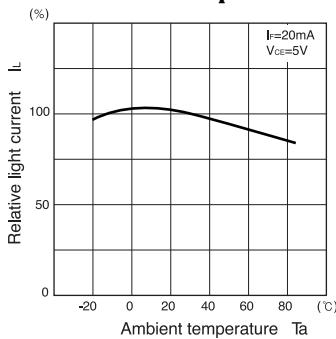
**Light current Vs.  
Forward current**



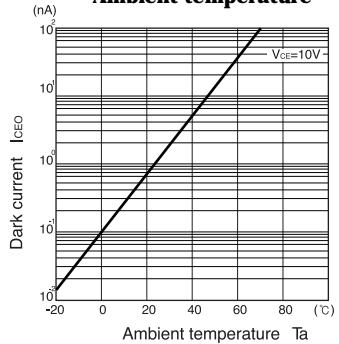
**Light current Vs.  
Collector-Emitter voltage**



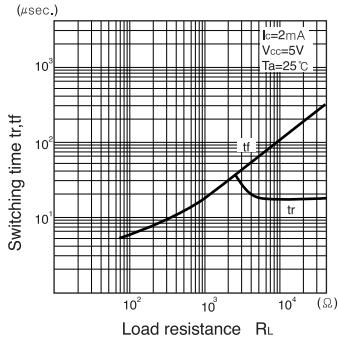
**Relative light current Vs.  
Ambient temperature**



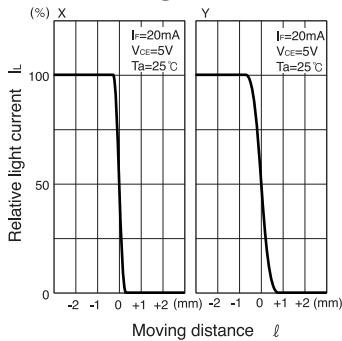
**Dark current Vs.  
Ambient temperature**



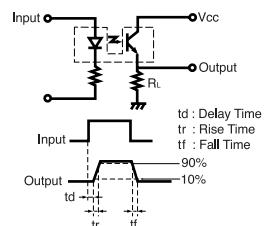
**Switching time Vs.  
Load resistance**



**Relative light current Vs.  
Moving distance**



Switching time measurement circuit



Method of measuring position detection characteristic

